2SC3941

Silicon NPN triple diffusion planar type

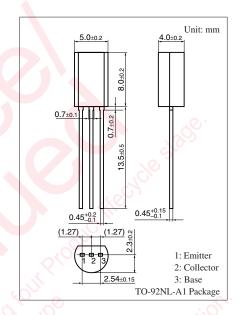
For high breakdown voltage general amplification For small TV video output Complementary to 2SA1858

■ Features

- \bullet High collector-emitter voltage (Base open) V_{CEO}
- High transition frequency f_T
- Allowing supply with the radial taping

■ Absolute Maximum Ratings $T_a = 25^{\circ}C$

Parameter	Symbol	Rating	Unit	
Collector-base voltage (Emitter open)	V_{CBO}	300	V	
Collector-emitter voltage (Base open)	V _{CEO}	300	V	
Emitter-base voltage (Collector open)	V_{EBO}	7	V	
Collector current	I_{C}	70	mA	
Peak collector current	I_{CP}	100	mA	
Collector power dissipation	P _C	1	W	
Junction temperature	Tj	150	°C	
Storage temperature	T _{stg}	-55 to +150	°C	
			2) (0	



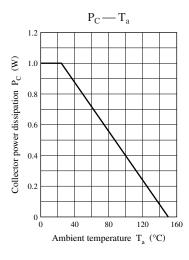
■ Electrical Characteristics T_a = 25°C ± 3°C

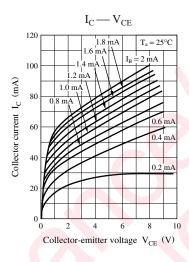
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector-emitter voltage (Base open)	V _{CEO}	$I_C = 100 \mu\text{A}, I_B = 0$	300	95		V
Emitter-base voltage (Collector open)	$V_{\rm EBO}$	$I_E = 1 \mu A, I_C = 0$	70			V
Collector-base cutoff current (Emitter open)	I_{CBO}	$V_{CB} = 100 \text{ V}, I_E = 0$	7.7		2	μΑ
Forward current transfer ratio *	h _{FE}	$V_{CE} = 10 \text{ V}, I_{C} = 5 \text{ mA}$	30		220	_
Collector-emitter saturation voltage	V _{CE(sat)}	$I_C = 50 \text{ mA}, I_B = 5 \text{ mA}$			1.2	V
Transition frequency	f_T	$V_{CB} = 10 \text{ V}, I_E = -10 \text{ mA}, f = 200 \text{ MHz}$	50	80		MHz
Collector output capacitance (Common base, input open circuited)	C _{ob}	$V_{CB} = 10 \text{ V}, I_E = 0, f = 1 \text{ MHz}$		4	8	pF
Storage time	t _{stg}	$I_C = 100 \text{ mA}, I_{B1} = 10 \text{ mA}, I_{B2} = 0$		2.5		μs

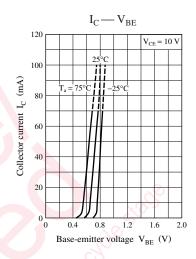
Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

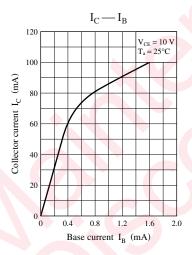
2. *: Rank classification

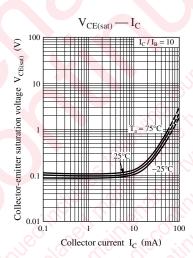
Rank	Р	Q	R
h_{FE}	30 to 100	60 to 150	100 to 220

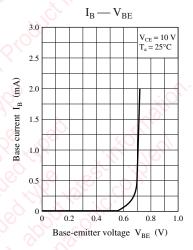


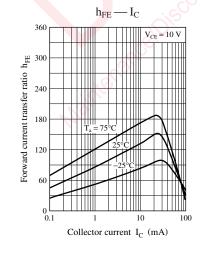


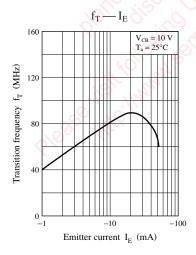


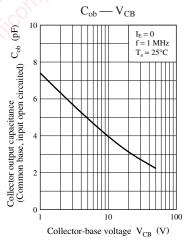




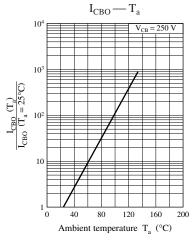


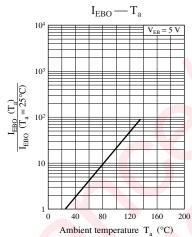


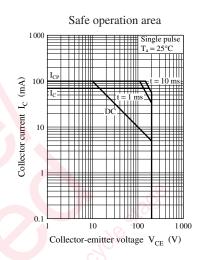




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